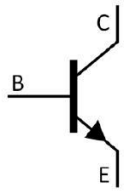
TO-126 NPN Silicon NPN transistor in a TO-126 Plastic Package.

$V_{CEO}$

High $V_{CEO}$ Large DC current, high $f_T$, low $V_{CE(sat)}$.

Low power audio amplifier, high speed switching applications.



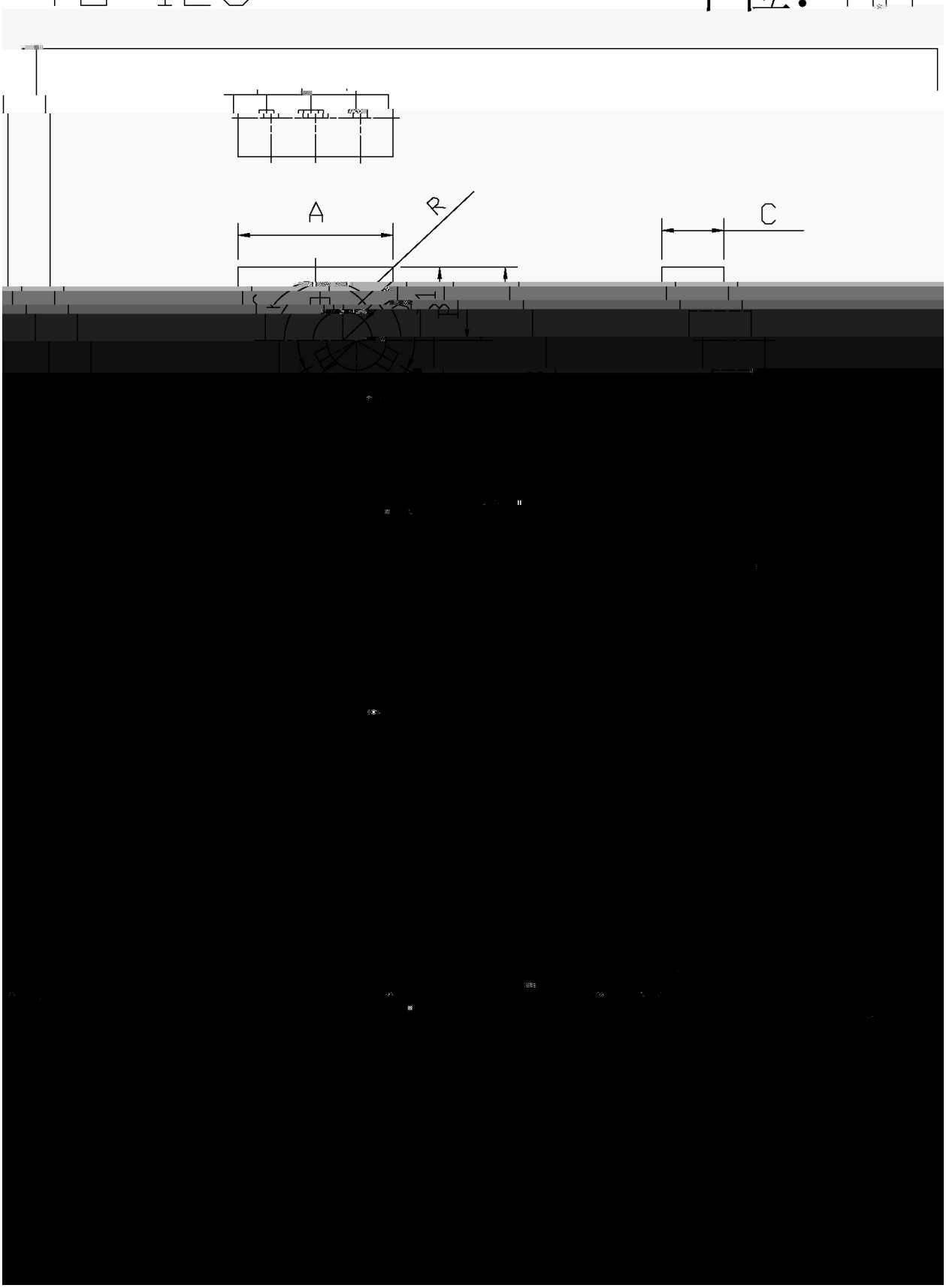


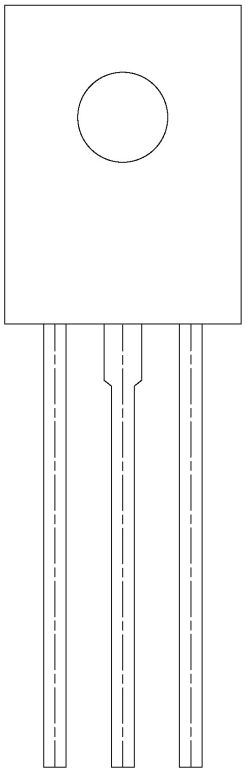

PIN1 Emitter PIN 2

| Parameter | Symbol | Rating | Unit |
|---|---|---|---|
| Collector to Base Voltage | $V_{CBO}$ | 100 | V |
| Collector to Emitter Voltage | $V_{CEO}$ | 100 | V |
| Emitter to Base Voltage | $V_{EBO}$ | 7.0 | V |

TO-126

单位：mm





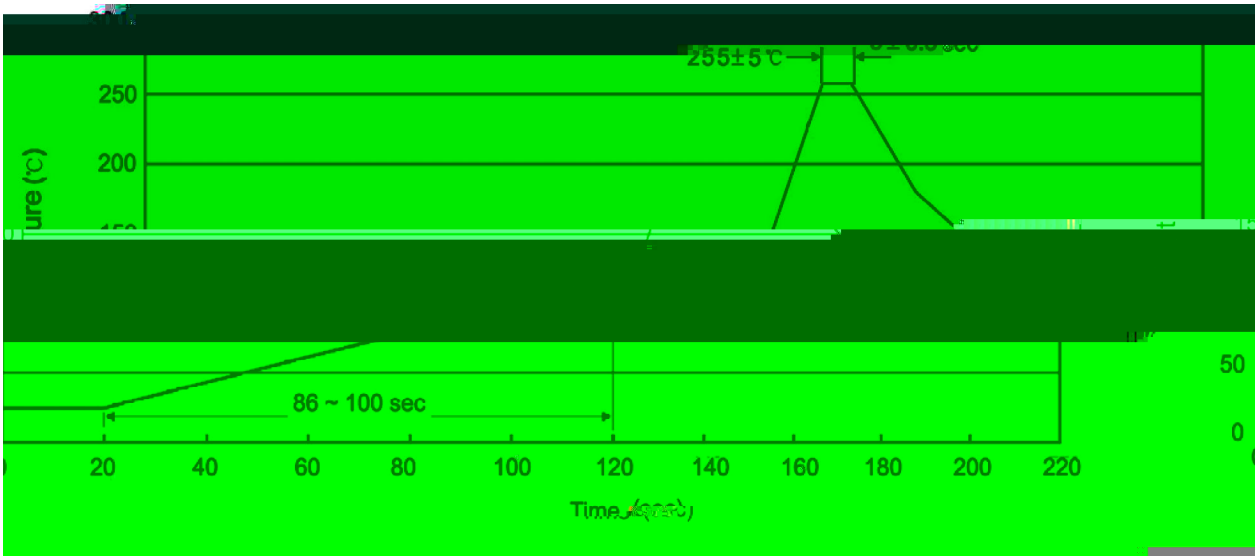
BR

MJE243

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Note:

BR:




| | | | | |
|---|---|---|---|---|
| | | | | Note: |
| 1 | 25 | 150 | 60 90sec; | 1.Preheating:25~150 , Time:60~90sec. |
| 2 | 255±5 | | 5±0.5sec; | 2.Peak Temp.:255±5 , Duration:5±0.5sec. |
| 3 | | 2 10 | /sec. | 3. Cooling Speed: 2~10 /sec. |

| | | | |
|---|---|---|---|
| 270±5 | 10±1 sec. | Temp.:270±5 | Time:10±1 sec |

/ BULK

| Package Type | Units | | | Dimension (unit mm$^3$) |
|---|---|---|---|---|
| | | | | |